

Darlington Transistors PNP Silicon

MPSA75 MPSA77

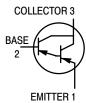
MAXIMUM RATINGS

Rating	Symbol	MPSA75	MPSA77	Unit
Collector–Emitter Voltage	V _{CES}	-40	Vdc	
Emitter-Base Voltage	V _{EBO}	-10		Vdc
Collector Current — Continuous	I _C	-500		Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0		mW mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W





ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage ($I_C = -100 \mu Adc, V_{BE} = 0$)	MPSA75 MPSA77	V _{(BR)CES}	-40 -60	_	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	MPSA75 MPSA77	V _{(BR)CBO}	-40 -60	_		Vdc
Collector Cutoff Current $(V_{CB} = -30 \text{ V}, I_E = 0)$ $(V_{CB} = -50 \text{ V}, I_E = 0)$	MPSA75 MPSA77	I _{CBO}	_ _	_ _	-100 -100	nAdc
Collector Cutoff Current ($V_{CE} = -30 \text{ V}, V_{BE} = 0$) ($V_{CE} = -50 \text{ V}, V_{BE} = 0$)	MPSA75 MPSA77	I _{CES}			-500 -500	nAdc
Emitter Cutoff Current (V _{EB} = -10 Vdc)		I _{EBO}	_	_	-100	nAdc
ON CHARACTERISTICS						
DC Current Gain $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$ $(I_C = -100 \text{ mA}, V_{CE} = -5.0 \text{ V})$		h _{FE}	10,000 10,000	_	_	_
Collector–Emitter Saturation Voltage (I _C = -	-100 mA, I _B = -0.1 mAdc)	V _{CE(sat)}	_	_	-1.5	Vdc
Base–Emitter On Voltage (I _C = –100 mA, V _{CE} = –5.0 Vdc)		V_{BE}	_	_	-2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Current-Gain — High Frequency (I _C = -10	mA, $V_{CE} = -5.0 \text{ V}$, $f = 100 \text{ MHz}$)	h _{fe}	1.25	2.4	_	_

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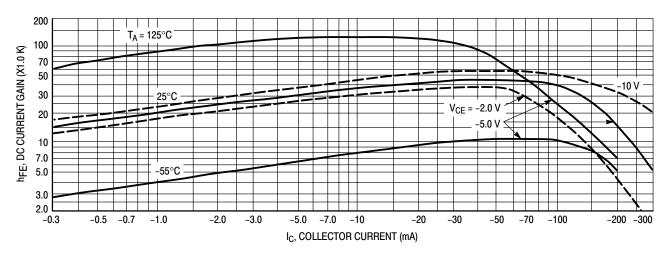


Figure 1. DC Current Gain

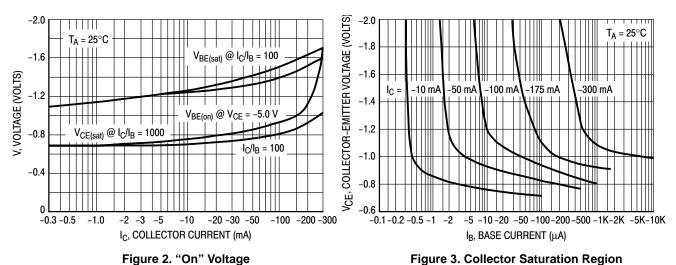


Figure 2. "On" Voltage

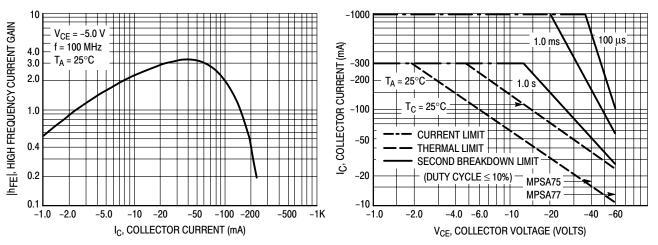


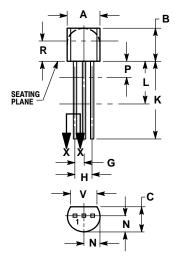
Figure 4. High Frequency Current Gain

Figure 5. Active Region, Safe Operating Area

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PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

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